NSN 5962-01-085-7962

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View Online at https://aerobasegroup.com/nsn/5962-01-085-7962

Overall Length:

22.1 millimeters

Overall Height:

8.2 millimeters

Overall Width:

7.9 millimeters

Body Length:

22.1 millimeters

Body Width:

6.6 millimeters

Body Height:

4.6 millimeters

Maximum Power Dissipation Rating:

0.5 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Bipolar and compatible dtl and high speed and expandable and monolithic

Inclosure Material:

Plastic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

11 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

4.5 volts power source

Time Rating Per Chacteristic:

40.00 nanoseconds propagation delay time, low to high level output and 40.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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